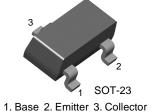


### BCW60A/B/C/D

### **General Purpose Transistor**



## **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	32	V
V <sub>CEO</sub>	Collector-Emitter Voltage	32	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	100	mA
P <sub>C</sub>	Collector Power Dissipation	350	mW
T <sub>STG</sub>	Storage Temperature	150	°C

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# **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =2mA, I <sub>B</sub> =0	32		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =1μA, I <sub>C</sub> =0	5		V
I <sub>CES</sub>	Collector Cut-off Current	V <sub>CE</sub> =32V, V <sub>BE</sub> =0		20	nA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =4V, I <sub>C</sub> =0		20	nA
h <sub>FE</sub>	DC Current Gain  : BCW60B : BCW60C : BCW60D : BCW60A : BCW60B : BCW60C : BCW60D : BCW60D : BCW60A : BCW60A : BCW60B : BCW60B	$V_{CE}$ =5V, $I_{C}$ =10 $\mu$ A $V_{CE}$ =5V, $I_{C}$ =2mA $V_{CE}$ =1V, $I_{C}$ =50mA	20 40 100 120 180 250 380 60 70 90 100	220 310 460 630	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =50mA, I <sub>B</sub> =1.25mA I <sub>C</sub> =10mA, I <sub>B</sub> =0.25mA		0.55 0.35	V V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =50mA, I <sub>B</sub> =1.25mA I <sub>C</sub> =10mA, I <sub>B</sub> =0.25mA	0.7 0.6	1.05 0.85	V V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA	0.55	0.75	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		4.5	pF
f <sub>T</sub>	Current Gain Bandwidth Product	I <sub>C</sub> =10mA, V <sub>CE</sub> =5V, f=100MHz	125		MHz
NF	Noise Figure	$I_C$ =0.2mA, $V_{CE}$ =5V R <sub>G</sub> =2K $\Omega$ , f=1KHz		6	dB
t <sub>ON</sub>	Turn On Time	I <sub>C</sub> =10mA, I <sub>B1</sub> =1mA		150	ns
t <sub>OFF</sub>	Turn Off Time	$V_{BB}$ =3.6V, $I_{B2}$ =1mA R1=R2=5K $\Omega$ , $R_L$ =990 $\Omega$		800	ns

# Marking Code

Туре	BCW60A	BCW60B	BCW60C	BCW60D
Mark.	AA	AB	AC	AD

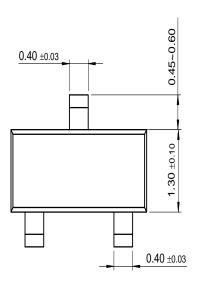


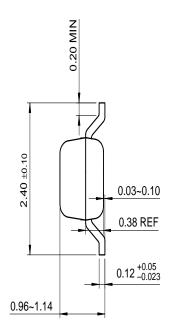


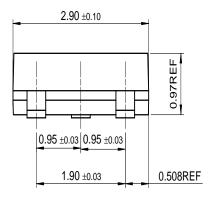
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## **Package Dimensions**

## **SOT-23**







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E <sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	$VCX^{TM}$
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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